

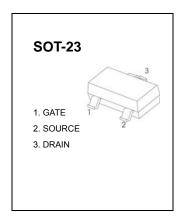
SOT-23 Plastic-Encapsulate MOSFETS

FEATURE

TrenchFET Power MOSFET

APPLICATIONS

- Load Switch for Portable Devices
- DC/DC Converter



MARKING: B4

Maximum ratings (T_a=25℃ unless otherwise noted)

Characteristic 特性參數	Symbol 符號	Max 最大値	Unit 單位
Drain-Source Voltage 漏極 - 源極電壓	$\mathrm{BV}_{\mathrm{DSS}}$	30	V
Gate- Source Voltage 栅極-源極電壓	$ m V_{GS}$	<u>+</u> 20	V
Drain Current (continuous) 漏極電流 -連續	I_D	5	A
Drain Current (pulsed) 漏極電流-脉冲	I_{DM}	18	A
Total Device Dissipation 總耗散功率 T _A =25℃環境溫度爲 25℃	P_{D}	1400	mW
Junction 結溫	$\mathrm{T}_{\mathtt{J}}$	150	$^{\circ}\! \mathbb{C}$
Storage Temperature 儲存溫度	T_{stg}	-55to+150	$^{\circ}\! \mathbb{C}$

Document ID	Issued Date	Revised Date	Revision	Page.
AS-3150012	2003/03/08	2012/05/16	D	3



SOT-23 Plastic-Encapsulate MOSFETS

Electrical characteristics (T_a=25°C unless otherwise noted)

Characteristic 特性參數	Symbol 符號	Min 最小値	Typ 典型値	Max 最大値	Unit 單位
Drain-Source Breakdown Voltage 漏極 - 源極擊穿電壓(I _D =250uA,V _{GS} =0V)	BVDSS	30			V
Gate Threshold Voltage 栅極開启電壓(I _D = 250uA,V _{GS} = V _{DS})	V _{GS(th)}	1		3	V
Diode Forward Voltage Drop 内附二極管正向壓降(Is= 1A,VGS=0V)	V _{SD}	_	0.7	1	V
Zero Gate Voltage Drain Current 零栅壓漏極電流(V _{GS} =0V, V _{DS} = 30V)	I _{DSS}	_	_	1	uA
Gate Body Leakage 栅極漏電流(V _{GS} =±20V, V _{DS} =0V)	I _{GSS}	_	_	<u>+</u> 100	nA
Static Drain-Source On-State Resistance 静态漏源導通電阻(I _D = 5A,V _{GS} =10V)	R _{DS(ON)}	_	25	28	m Ω
Static Drain-Source On-State Resistance 静态漏源導通電阻(I _D = 3A,V _{GS} =4.5V)	R _{DS(ON)}		40	45	${\tt m}\Omega$
Input Capacitance 輸入電容 (V _{GS} =0V, V _{DS} = 15V,f=1MHz)	C _{ISS}	_	545	_	pF
Output Capacitance 輸出電容 (V _{GS} =0V, V _{DS} = 15V,f=1MHz)	Coss	_	66	_	pF
Turn-ON Time 开启時間 (V _{DS} = 15V, V _{GS} = 10V, R _{GEN} =6Ω)	t(on)		9.6	_	ns
Turn-OFF Time 关断時間 (V _{DS} = 15V, V _{GS} = 10V, R _{GEN} =6Ω)	t(off)		39	_	ns

Pulse Width≤300 *μ* s; Duty Cycle≤2.0%

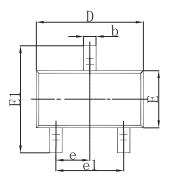


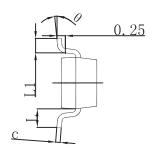
Document ID	Issued Date	Revised Date	Revision	Page.
AS-3150012	2003/03/08	2012/05/16	D	3

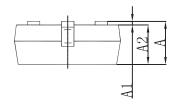


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SOT-23 Package Outline Dimensions

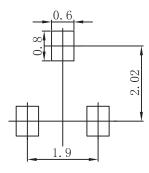






Cumbal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

SOT-23 Suggested Pad Layout



- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.



Document ID	Issued Date	Revised Date	Revision	Page.
AS-3150012	2003/03/08	2012/05/16	D	3